

SCT3080KR

N-channel SiC power MOSFET

V _{DSS}	1200V
R _{DS(on)} (Typ.)	80mΩ
I_{D}^{*1}	31A
P _D	165W

Features

- 1) Low on-resistance
- 2) Fast switching speed
- 3) Fast reverse recovery
- 4) Easy to parallel
- 5) Simple to drive
- 6) Pb-free lead plating ; RoHS compliant

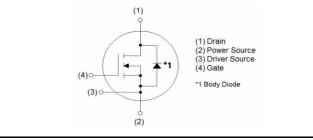
Application

- Solar inverters
- DC/DC converters
- Switch mode power supplies
- Induction heating
- Motor drives

Outline



Inner circuit



Please note Driver Source and Power Source are not exchangeable. Their exchange might lead to malfunction.

Packaging specifications

	Packing	Tube
	Reel size (mm)	-
Tuno	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	30
	Taping code	C15
	Marking	SCT3080KR

●Absolute maximum ratings (T_{vi} = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit	
Drain - Source Voltage		V _{DSS}	1200	V	
Continuous Drain current	$T_c = 25^{\circ}C$	I _D ^{*1}	31	А	
Continuous Drain current	T _c = 100°C	I _D ^{*1}	22	А	
Pulsed Drain current (T _c = 25°C)		I _{D,pulse} ^{*2}	77	Α	
Gate - Source voltage (DC)		V _{GSS}	-4 to +22	V	
Gate - Source surge voltage (t _{surge} < 300ns)		*3 V _{GSS_surge}	-4 to +26	V	
Recommended drive voltage		V _{GS_op} ^{*4}	0 / +18	V	
Virtual Junction temperature		T _{vj}	175	°C	
Range of storage temperature		T _{stg}	-55 to +175	°C	

SCT3080KR

•Electrical characteristics ($T_{vj} = 25^{\circ}C$ unless otherwise specified)

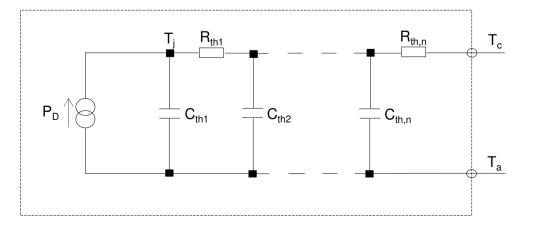
Parameter	Symbol	Symbol Conditions		Values			
Farameler	Symbol Conditions		Min.	Тур.	Max.	Unit	
		$V_{GS} = 0V, I_D = 1mA$					
Drain - Source breakdown voltage	$V_{(BR)DSS}$	$T_{vj} = 25^{\circ}C$	1200	-	-	V	
		$T_{vj} = -55^{\circ}C$	1200	-	-		
		$V_{GS} = 0V, V_{DS} = 1200V$					
Zero Gate voltage Drain current	I _{DSS}	$T_{vj} = 25^{\circ}C$	-	1	10	μA	
		$T_{vj} = 150^{\circ}C$	-	2	-		
Gate - Source leakage current	I _{GSS+}	$V_{GS} = +22V, \ V_{DS} = 0V$	-	-	100	nA	
Gate - Source leakage current	I _{GSS-}	$V_{GS} = -4V, V_{DS} = 0V$	-	-	-100	nA	
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = 10V, I_D = 5mA$	2.7	-	5.6	V	
		$V_{GS} = 18V, I_{D} = 10A$					
Static Drain - Source on - state resistance	${\sf R}_{\sf DS(on)}$ *5	$T_{vj} = 25^{\circ}C$	-	80	104	mΩ	
		T _{vj} = 150°C	-	136	-		
Gate input resistance	R _G	f = 1MHz, open drain	-	12	-	Ω	

Thermal resistance

Parameter	Symbol	Values			Unit
i arameter	Symbol	Min.	Тур.	Max.	Onit
Thermal resistance, junction - case	R _{thJC}	-	0.70	0.91	K/W

•Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R _{th1}	8.52×10 -2		C _{th1}	1.22×10 ⁻³	
R _{th2}	4.15×10 ⁻¹	K/W	C_{th2}	6.20×10 ⁻³	Ws/K
R _{th3}	2.06×10 ⁻¹		$C_{\text{th}3}$	3.49×10 ⁻²	





$\bullet \textbf{Electrical characteristics}$ (T_vj = 25 \oplus C unless otherwise specified)

Doromotor	Symbol	Conditions	Values			1.1
Parameter	Symbol Conditions		Min.	Тур.	Max.	Unit
Transconductance	g _{fs} *5	$V_{DS} = 10V, I_{D} = 10A$	-	4.4	-	S
Input capacitance	C _{iss}	$V_{GS} = 0V$	-	785	-	
Output capacitance	C _{oss}	V _{DS} = 800V	-	75	-	pF
Reverse transfer capacitance	C_{rss}	f = 1MHz	-	35	-	
Effective output capacitance, energy related	$C_{o(er)}$	$V_{GS} = 0V$ $V_{DS} = 0V$ to 600V	-	74	_	pF
Total Gate charge	Q_g^{*5}	$V_{DS} = 600V$ $I_{D} = 10A$	-	60	-	
Gate - Source charge	Q _{gs} *5	$V_{\rm GS} = 18V$	-	11	-	nC
Gate - Drain charge	Q_{gd} *5	See Fig. 1-1.	_	31	-	
Turn - on delay time	t _{d(on)} *5	$V_{DS} = 600V$ $I_{D} = 15A$	-	5	-	
Rise time	t _r *5	V _{GS} = 0V/+18V	-	14	-	20
Turn - off delay time	$t_{d(off)}$ *5	$R_{G} = 0\Omega, L = 750 \mu H$ L _σ = 50nH, C _σ = 10pF	-	19	-	ns
Fall time	t _f *5	See Fig. 2-1, 2-2, 2-3.	-	13	-	
Turn - on switching loss	${\sf E_{on}}^{*5}$	E _{on} includes diode reverse recovery.	-	168	-	
Turn - off switching loss	${\sf E}_{\sf off}$ *5		-	21	-	μJ



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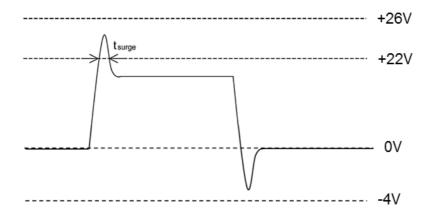
●Body diode electrical characteristics (Source-Drain) (T_{vj} = 25°C unless otherwise specified)

Parameter	Symbol	Symbol Conditions		Values		
Farameler	Symbol	Conditions	Min.	Тур.	Max.	Unit
Body diode continuous, forward current	ا _S *1	T _c = 25°C	-	-	31	А
Body diode direct current, pulsed	I _{SM} *2	T _c = 25 0	-	-	77	А
Forward voltage	V_{SD} *5	$V_{GS} = 0V, I_{S} = 10A$	-	3.2	-	V
Reverse recovery time	t _{rr} *5	$I_{\rm F} = 10A$ $V_{\rm B} = 600V$	-	17	-	ns
Reverse recovery charge	Q _{rr} *5	v _R = 000∨ di/dt = 2500A/µs	-	261	-	nC
Peak reverse recovery current	I _{rrm} *5	$L_{\sigma} = 50$ nH, $C_{\sigma} = 10$ pF See Fig. 3-1, 3-2.	-	26	-	А

*1 Limited by maximum T_{vj} and for Max. R_{thJC} .

*2 PW \leq 10µs, Duty cycle \leq 1%

*3 Example of acceptable V_{GS} waveform

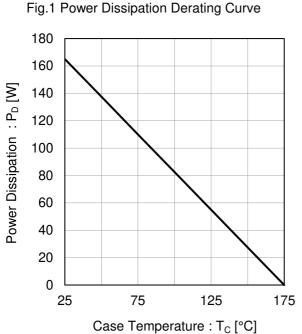


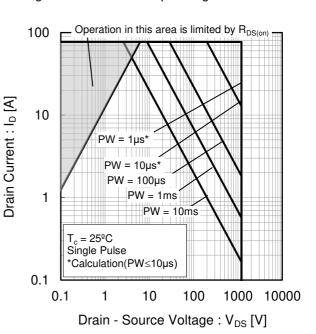
Please note especially when using driver source that $V_{\text{GSS_surge}}$ must be in the range of absolute maximum rating.

*4 Please be advised not to use SiC-MOSFETs with V_{GS} below 13V as doing so may cause thermal runaway.

*5 Pulsed







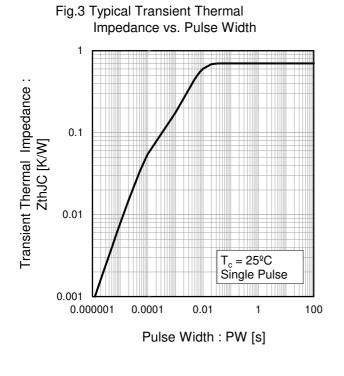
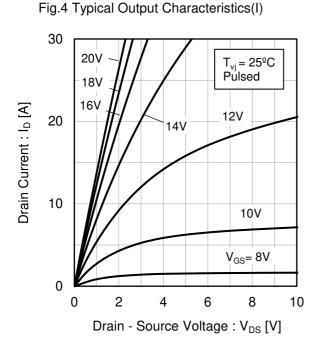


Fig.2 Maximum Safe Operating Area





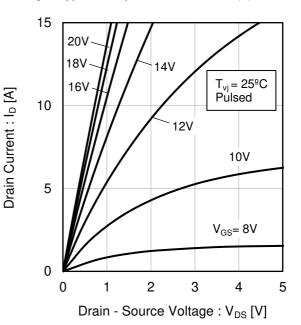


Fig.5 Typical Output Characteristics(II)

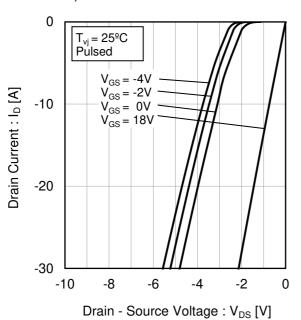
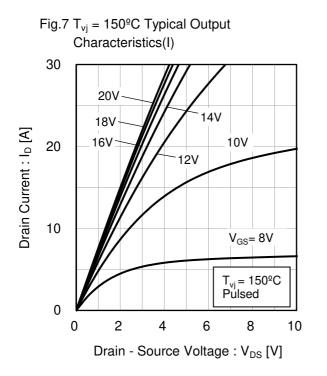
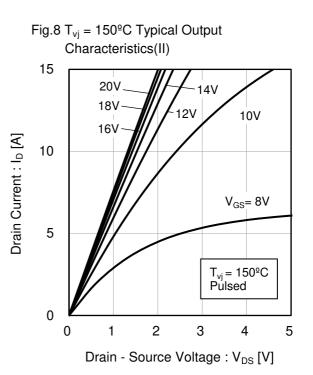


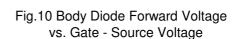
Fig.6 T_{vj} = 25ºC 3rd Quadrant Characteristics

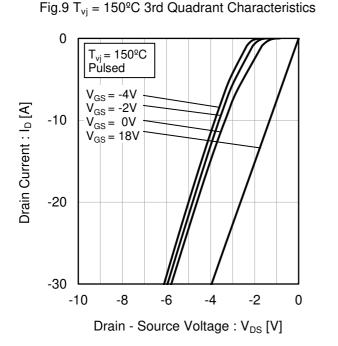
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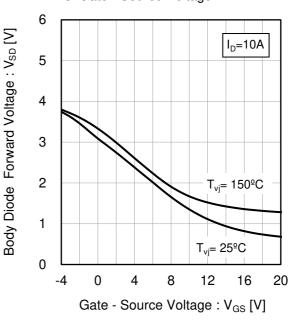














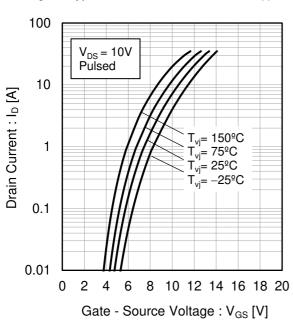
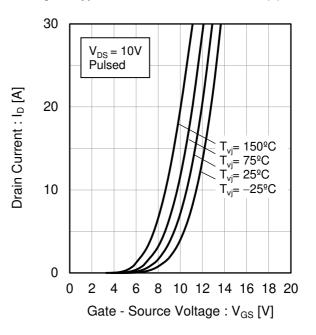


Fig.11 Typical Transfer Characteristics (I)

Fig.12 Typical Transfer Characteristics (II)



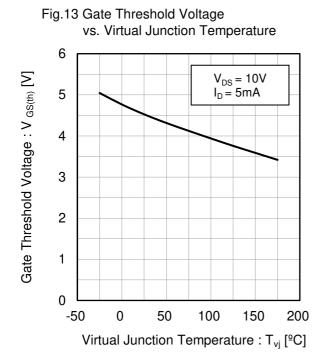
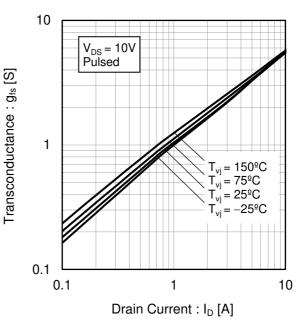
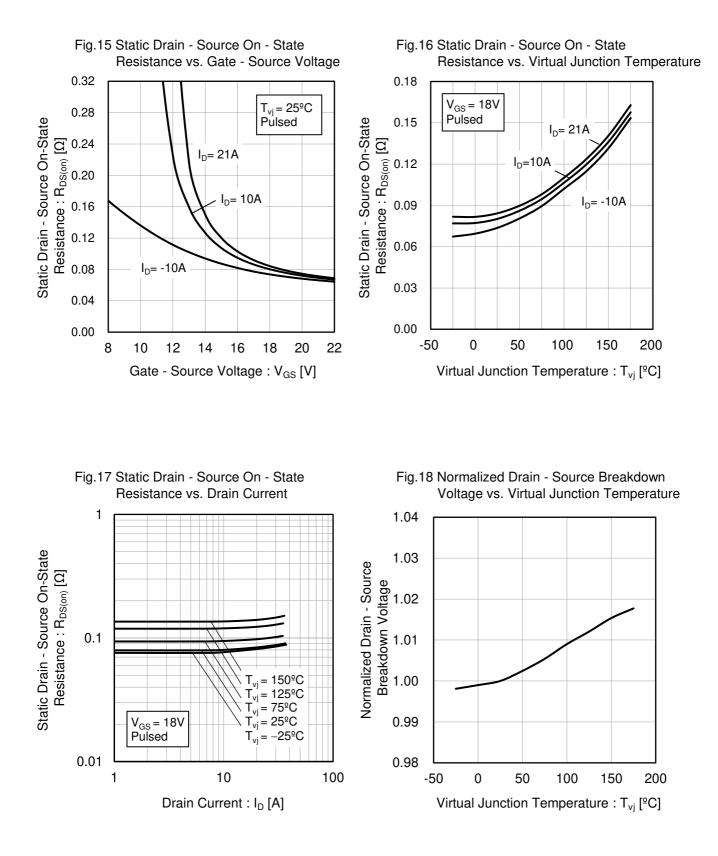


Fig.14 Transconductance vs. Drain Current









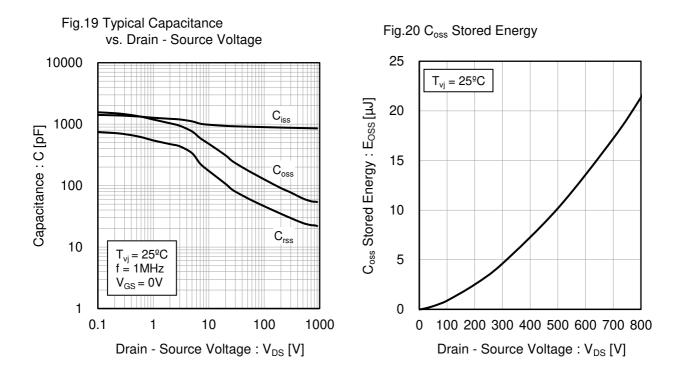
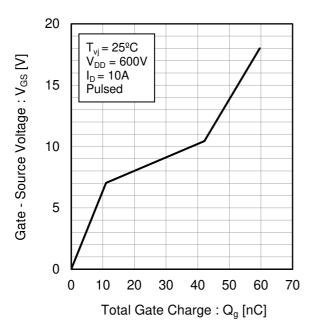
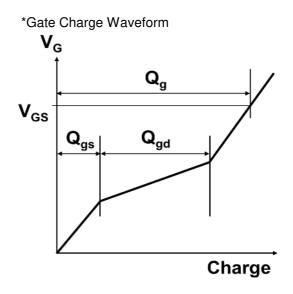


Fig.21 Dynamic Input Characteristics



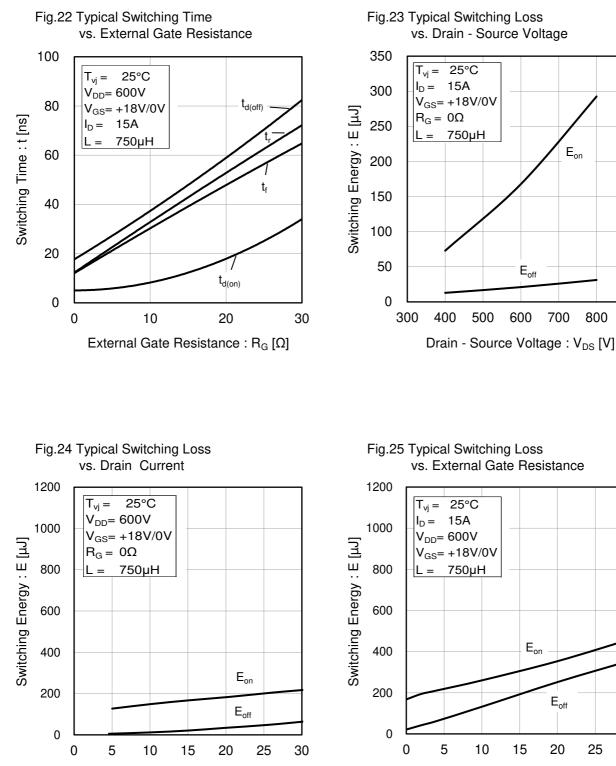




800

900

Electrical characteristic curves



External Gate Resistance : $R_G [\Omega]$

Drain Current : I_D [A]



25

30

Measurement circuits and waveforms

Fig.1-1 Gate Charge Measurement Circuit

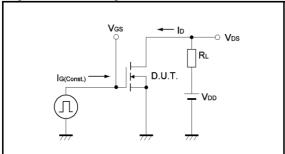


Fig.2-1 Switching Characteristics Measurement Circuit

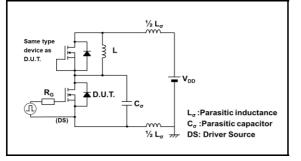


Fig.2-3 Waveforms for Switching Energy Loss

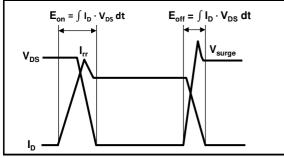


Fig.3-1 Reverse Recovery Time Measurement Circuit

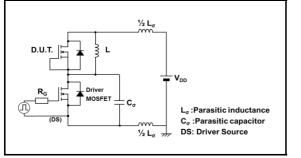


Fig.2-2 Waveforms for Switching Time

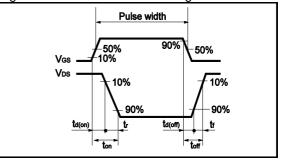
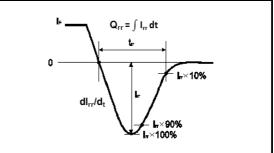
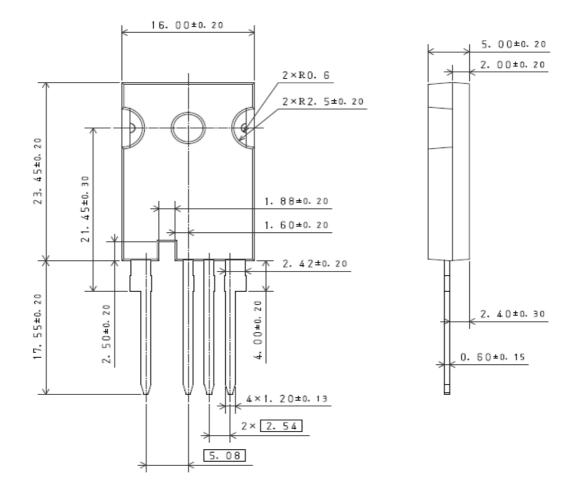


Fig.3-2 Reverse Recovery Waveform



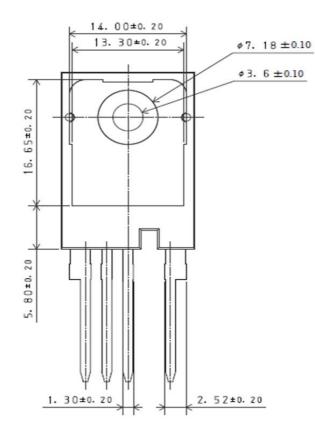


Package Dimensions



Unit: mm

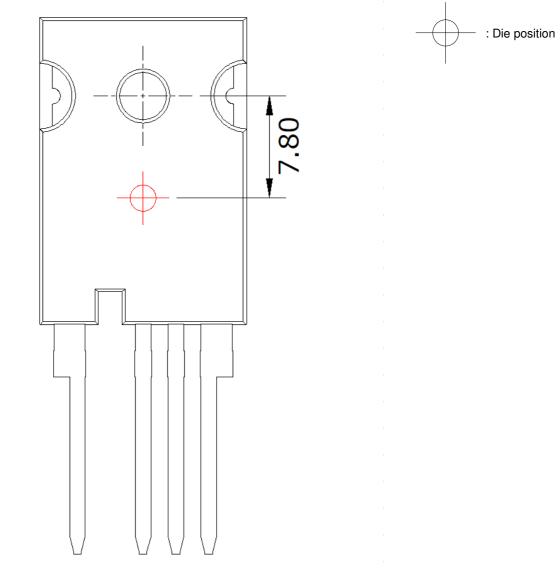




Unit: mm



Die Bonding Layout



• Front view of the packaging.

•Dimensions are design values.

• If the heat sink is to be installed, it should be in contact with the die bonding point.

Unit: mm



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